



# 1-Mbps QUAD DIGITAL ISOLATORS

Check for Samples: [ISO7241A-EP](#)

## FEATURES

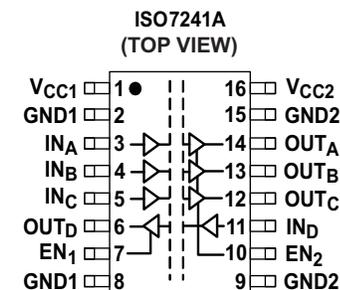
- 4000- $V_{\text{peak}}$  Isolation, 560- $V_{\text{peak}}$   $V_{\text{IORM}}$ 
  - UL 1577, IEC 60747-5-2 (VDE 0884, Rev 2), IEC 61010-1, IEC 60950-1 and CSA Approved
- 4-kV ESD Protection
- Operates With 3.3-V or 5-V Supplies
- Typical 25-Year Life at Rated Working Voltage (See Application Note ([SLLA197](#)) and [Figure 10](#))
- High Electromagnetic Immunity (See Application Report ([SLLA181](#)))

## APPLICATIONS

- Industrial Fieldbus
- Computer Peripheral Interface
- Servo Control Interface
- Data Acquisition

## SUPPORTS DEFENSE, AEROSPACE, AND MEDICAL APPLICATIONS

- Controlled Baseline
- One Assembly/Test Site
- One Fabrication Site
- Available in Military ( $-55^{\circ}\text{C}/125^{\circ}\text{C}$ ) Temperature Range<sup>(1)</sup>
- Extended Product Life Cycle
- Extended Product-Change Notification
- Product Traceability



(1) Additional temperature ranges available - contact factory

## DESCRIPTION

See the [Product Notification](#) section. The ISO7241A is a quad-channel digital isolator with multiple channel configurations and output enable functions. This device has logic input and output buffers separated by TI's silicon dioxide ( $\text{SiO}_2$ ) isolation barrier. Used in conjunction with isolated power supplies, this device blocks high voltage, isolate grounds, and prevent noise currents from entering the local ground and interfering with or damaging sensitive circuitry.

The ISO7241A has three channels the same direction and one channel in opposition.

This device has TTL input thresholds and a noise-filter at the input that prevents transient pulses from being passed to the output of the device.

A periodic update pulse is sent across the barrier to ensure the proper dc level of the output. If this dc-refresh pulse is not received, the input is assumed to be unpowered or not being actively driven, and the failsafe circuit drives the output to a logic high state. (See ISO7240CF ([SLLS869](#)) or contact TI for a logic low failsafe option).

The ISO7241A may be powered from either 3.3-V or 5-V supplies on either side in any 3.3-V / 3.3-V, 5-V / 5-V, 5-V / 3.3-V, or 3.3-V / 5-V combination. Note that the signal input pins are 5-V tolerant regardless of the voltage supply level being used.

This device is characterized for operation over the ambient temperature range of  $-55^{\circ}\text{C}$  to  $125^{\circ}\text{C}$ .



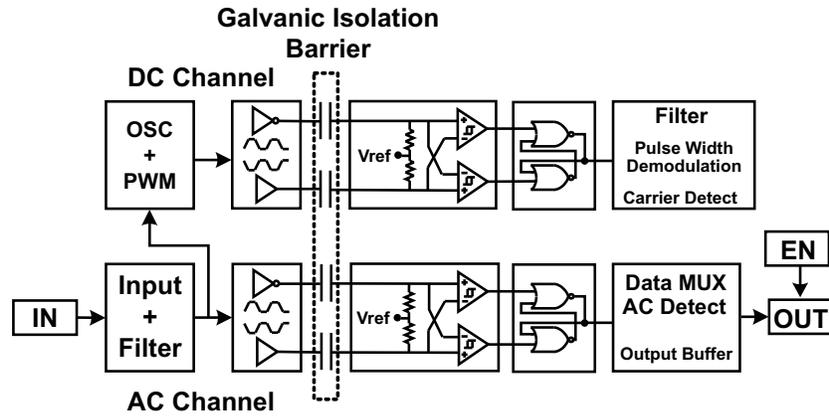
Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

**FUNCTION DIAGRAM**



**Table 1. Device Function Table<sup>(1)</sup>**

INPUT V <sub>CC</sub>	OUTPUT V <sub>CC</sub>	INPUT (IN)	OUTPUT ENABLE (EN)	OUTPUT (OUT)
PU	PU	H	H or Open	H
		L	H or Open	L
		X	L	Z
		Open	H or Open	H
PD	PU	X	H or Open	H
PD	PU	X	L	Z

(1) PU = Powered Up; PD = Powered Down ; X = Irrelevant; H = High Level; L = Low Level

**Table 2. ORDERING INFORMATION<sup>(1)</sup>**

T <sub>A</sub>	PACKAGE <sup>(2)</sup>		ORDERABLE PART NUMBER	TOP-SIDE MARKING
-55°C to 125°C	DW	Reel	ISO7241AMDWREP	ISO7241AM

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI Web site at [www.ti.com](http://www.ti.com).

(2) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at [www.ti.com/sc/package](http://www.ti.com/sc/package).

**ABSOLUTE MAXIMUM RATINGS<sup>(1)</sup>**

			VALUE	UNIT		
V <sub>CC</sub>	Supply voltage <sup>(2)</sup> , V <sub>CC1</sub> , V <sub>CC2</sub>		–0.5 to 6	V		
V <sub>I</sub>	Voltage at IN, OUT, EN		–0.5 to 6	V		
I <sub>O</sub>	Output current		±15	mA		
ESD	Electrostatic discharge	Human Body Model	JEDEC Standard 22, Test Method A114-C.01	All pins	±4	kV
		Field-Induced-Charged Device Model	JEDEC Standard 22, Test Method C101		±1	
		Machine Model	ANSI/ESDS5.2-1996		±200	V
T <sub>J</sub>	Maximum junction temperature		170	°C		

- (1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values are with respect to network ground terminal and are peak voltage values.

**RECOMMENDED OPERATING CONDITIONS**

		MIN	TYP	MAX	UNIT
V <sub>CC</sub>	Supply voltage <sup>(1)</sup> , V <sub>CC1</sub> , V <sub>CC2</sub>	3.15		5.5	V
I <sub>OH</sub>	High-level output current			4	mA
I <sub>OL</sub>	Low-level output current	–4			mA
t <sub>ui</sub>	Input pulse width	1			µs
1/t <sub>ui</sub>	Signaling rate	0		1000	kbps
V <sub>IH</sub>	High-level input voltage (IN) (EN on all devices)	2		V <sub>CC</sub>	V
V <sub>IL</sub>	Low-level input voltage (IN) (EN on all devices)	0		0.8	V
T <sub>J</sub>	Junction temperature			150	°C
H	External magnetic field-strength immunity per IEC 61000-4-8 and IEC 61000-4-9 certification			1000	A/m

- (1) For the 5-V operation, V<sub>CC1</sub> or V<sub>CC2</sub> is specified from 4.5 V to 5.5 V.  
For the 3-V operation, V<sub>CC1</sub> or V<sub>CC2</sub> is specified from 3.15 V to 3.6 V.

**ELECTRICAL CHARACTERISTICS:  $V_{CC1}$  and  $V_{CC2}$  at 5-V<sup>(1)</sup> OPERATION**

, over recommended operating conditions (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b>SUPPLY CURRENT</b>						
$I_{CC1}$	Quiescent	$V_I = V_{CC}$ or 0 V, All channels, no load, EN <sub>1</sub> at 3 V, EN <sub>2</sub> at 3 V		6.5	11	mA
	1 Mbps					
$I_{CC2}$	Quiescent	$V_I = V_{CC}$ or 0 V, All channels, no load, EN <sub>1</sub> at 3 V, EN <sub>2</sub> at 3 V		13	20	mA
	1 Mbps					
<b>ELECTRICAL CHARACTERISTICS</b>						
$I_{OFF}$	Sleep mode output current	EN at 0 V, Single channel		0		μA
$V_{OH}$	High-level output voltage	$I_{OH} = -4$ mA, See <a href="#">Figure 1</a>	$V_{CC} - 0.8$			V
		$I_{OH} = -20$ μA, See <a href="#">Figure 1</a>	$V_{CC} - 0.1$			
$V_{OL}$	Low-level output voltage	$I_{OL} = 4$ mA, See <a href="#">Figure 1</a>			0.4	V
		$I_{OL} = 20$ μA, See <a href="#">Figure 1</a>			0.1	
$V_{I(HYS)}$	Input voltage hysteresis			150		mV
$I_{IH}$	High-level input current	IN from 0 V to $V_{CC}$			10	μA
$I_{IL}$	Low-level input current				-10	
$C_1$	Input capacitance to ground	IN at $V_{CC}$ , $V_I = 0.4 \sin(4E6\pi t)$			2	pF
CMTI	Common-mode transient immunity	$V_I = V_{CC}$ or 0 V, See <a href="#">Figure 4</a>	25	50		kV/μs

- (1) For the 5-V operation,  $V_{CC1}$  or  $V_{CC2}$  is specified from 4.5 V to 5.5 V.  
For the 3-V operation,  $V_{CC1}$  or  $V_{CC2}$  is specified from 3.15 V to 3.6 V.

**SWITCHING CHARACTERISTICS:  $V_{CC1}$  and  $V_{CC2}$  at 5-V OPERATION**

over recommended operating conditions (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT	
$t_{PLH}$ , $t_{PHL}$	Propagation delay	See <a href="#">Figure 1</a>	40		95	ns	
PWD	Pulse-width distortion <sup>(1)</sup> $ t_{PHL} - t_{PLH} $				10		
$t_{sk(o)}$	Channel-to-channel output skew <sup>(2)</sup>				2	ns	
$t_r$	Output signal rise time	See <a href="#">Figure 1</a>			2	ns	
$t_f$	Output signal fall time				2		
$t_{PHZ}$	Propagation delay, high-level-to-high-impedance output	See <a href="#">Figure 2</a>			15	ns	
$t_{PZH}$	Propagation delay, high-impedance-to-high-level output				15		20
$t_{PLZ}$	Propagation delay, low-level-to-high-impedance output				15		20
$t_{PZL}$	Propagation delay, high-impedance-to-low-level output				15		20
$t_{fs}$	Failsafe output delay time from input power loss	See <a href="#">Figure 3</a>			12	μs	

- (1) Also referred to as pulse skew.  
(2)  $t_{sk(o)}$  is the skew between specified outputs of a single device with all driving inputs connected together and the outputs switching in the same direction while driving identical specified loads.

**ELECTRICAL CHARACTERISTICS:  $V_{CC1}$  at 5-V,  $V_{CC2}$  at 3.3-V<sup>(1)</sup> OPERATION**

over recommended operating conditions (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b>SUPPLY CURRENT</b>						
$I_{CC1}$	Quiescent	$V_1 = V_{CC}$ or 0 V, All channels, no load, EN <sub>1</sub> at 3 V, EN <sub>2</sub> at 3 V		6.5	11	mA
	1 Mbps					
$I_{CC2}$	Quiescent	$V_1 = V_{CC}$ or 0 V, All channels, no load, EN <sub>1</sub> at 3 V, EN <sub>2</sub> at 3 V		8	13	mA
	1 Mbps			8	13	
<b>ELECTRICAL CHARACTERISTICS</b>						
$I_{OFF}$	Sleep mode output current	EN at 0 V, Single channel		0		$\mu$ A
$V_{OH}$	High-level output voltage	$I_{OH} = -4$ mA, See <a href="#">Figure 1</a>	(5-V side)		$V_{CC} - 0.8$	V
		$I_{OH} = -20$ $\mu$ A, See <a href="#">Figure 1</a>			$V_{CC} - 0.1$	
$V_{OL}$	Low-level output voltage	$I_{OL} = 4$ mA, See <a href="#">Figure 1</a>			0.4	V
		$I_{OL} = 20$ $\mu$ A, See <a href="#">Figure 1</a>			0.1	
$V_{I(HYS)}$	Input voltage hysteresis		150			mV
$I_{IH}$	High-level input current	IN from 0 V to $V_{CC}$			10	$\mu$ A
$I_{IL}$	Low-level input current		-10			
$C_1$	Input capacitance to ground	IN at $V_{CC}$ , $V_I = 0.4 \sin(4E6\pi t)$			2	pF
CMTI	Common-mode transient immunity	$V_1 = V_{CC}$ or 0 V, See <a href="#">Figure 4</a>	25	50		kV/ $\mu$ s

- (1) For the 5-V operation,  $V_{CC1}$  or  $V_{CC2}$  is specified from 4.5 V to 5.5 V.  
For the 3-V operation,  $V_{CC1}$  or  $V_{CC2}$  is specified from 3.15 V to 3.6 V.

**SWITCHING CHARACTERISTICS:  $V_{CC1}$  at 5-V,  $V_{CC2}$  at 3.3-V OPERATION**

over recommended operating conditions (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
$t_{PLH}$ , $t_{PHL}$	Propagation delay	See <a href="#">Figure 1</a>	40		100	ns
PWD	Pulse-width distortion <sup>(1)</sup> $ t_{PHL} - t_{PLH} $				11	
$t_{sk(o)}$	Channel-to-channel output skew <sup>(2)</sup>				3	ns
$t_r$	Output signal rise time	See <a href="#">Figure 1</a>			2	ns
$t_f$	Output signal fall time				2	
$t_{PHZ}$	Propagation delay, high-level-to-high-impedance output	See <a href="#">Figure 2</a>			15	ns
$t_{PZH}$	Propagation delay, high-impedance-to-high-level output				15	
$t_{PLZ}$	Propagation delay, low-level-to-high-impedance output				15	
$t_{PZL}$	Propagation delay, high-impedance-to-low-level output				15	
$t_{fs}$	Failsafe output delay time from input power loss	See <a href="#">Figure 3</a>			18	$\mu$ s

- (1) Also known as pulse skew  
(2)  $t_{sk(o)}$  is the skew between specified outputs of a single device with all driving inputs connected together and the outputs switching in the same direction while driving identical specified loads.

**ELECTRICAL CHARACTERISTICS:  $V_{CC1}$  at 3.3-V,  $V_{CC2}$  at 5-V<sup>(1)</sup> OPERATION**

over recommended operating conditions (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b>SUPPLY CURRENT</b>						
$I_{CC1}$	Quiescent	$V_I = V_{CC}$ or 0 V, All channels, no load, EN <sub>1</sub> at 3 V, EN <sub>2</sub> at 3 V		4	7	mA
	1 Mbps			4	7	
$I_{CC2}$	Quiescent	$V_I = V_{CC}$ or 0 V, All channels, no load, EN <sub>1</sub> at 3 V, EN <sub>2</sub> at 3 V		13	20	mA
	1 Mbps			13	20	
<b>ELECTRICAL CHARACTERISTICS</b>						
$I_{OFF}$	Sleep mode output current	EN at $V_{CC}$ , Single channel		0		$\mu$ A
$V_{OH}$	High-level output voltage	$I_{OH} = -4$ mA, See <a href="#">Figure 1</a>	(5-V side)		$V_{CC} - 0.8$	V
		$I_{OH} = -20$ $\mu$ A, See <a href="#">Figure 1</a>			$V_{CC} - 0.1$	
$V_{OL}$	Low-level output voltage	$I_{OL} = 4$ mA, See <a href="#">Figure 1</a>			0.4	V
		$I_{OL} = 20$ $\mu$ A, See <a href="#">Figure 1</a>			0.1	
$V_{I(HYS)}$	Input voltage hysteresis				150	mV
$I_{IH}$	High-level input current	IN from 0 V to $V_{CC}$			10	$\mu$ A
$I_{IL}$	Low-level input current				-10	
$C_1$	Input capacitance to ground	IN at $V_{CC}$ , $V_I = 0.4 \sin(4E6\pi t)$			2	pF
CMTI	Common-mode transient immunity	$V_I = V_{CC}$ or 0 V, See <a href="#">Figure 4</a>	25	50		kV/ $\mu$ s

- (1) For the 5-V operation,  $V_{CC1}$  or  $V_{CC2}$  is specified from 4.5 V to 5.5 V.  
 For the 3-V operation,  $V_{CC1}$  or  $V_{CC2}$  is specified from 3.15 V to 3.6 V.

**SWITCHING CHARACTERISTICS:  $V_{CC1}$  at 3.3-V and  $V_{CC2}$  at 5-V OPERATION**

over recommended operating conditions (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
$t_{PLH}$ , $t_{PHL}$	Propagation delay	See <a href="#">Figure 1</a>	40		100	ns
PWD	Pulse-width distortion <sup>(1)</sup> $ t_{PHL} - t_{PLH} $				11	
$t_{sk(o)}$	Channel-to-channel output skew <sup>(2)</sup>				2.5	ns
$t_r$	Output signal rise time	See <a href="#">Figure 1</a>			2	ns
$t_f$	Output signal fall time				2	
$t_{PHZ}$	Propagation delay, high-level-to-high-impedance output	See <a href="#">Figure 2</a>			15	ns
$t_{PZH}$	Propagation delay, high-impedance-to-high-level output				15	
$t_{PLZ}$	Propagation delay, low-level-to-high-impedance output				15	
$t_{PZL}$	Propagation delay, high-impedance-to-low-level output				15	
$t_{fs}$	Failsafe output delay time from input power loss	See <a href="#">Figure 3</a>			12	$\mu$ s

- (1) Also known as pulse skew  
 (2)  $t_{sk(o)}$  is the skew between specified outputs of a single device with all driving inputs connected together and the outputs switching in the same direction while driving identical specified loads.

**ELECTRICAL CHARACTERISTICS:  $V_{CC1}$  and  $V_{CC2}$  at 3.3 V<sup>(1)</sup> OPERATION**

over recommended operating conditions (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b>SUPPLY CURRENT</b>						
$I_{CC1}$	Quiescent	$V_1 = V_{CC}$ or 0 V, all channels, no load, EN <sub>1</sub> at 3 V, EN <sub>2</sub> at 3 V		4	7	mA
	1 Mbps			4	7	
$I_{CC2}$	Quiescent	$V_1 = V_{CC}$ or 0 V, all channels, no load, EN <sub>1</sub> at 3 V, EN <sub>2</sub> at 3 V		8	13	mA
	1 Mbps			8	13	
<b>ELECTRICAL CHARACTERISTICS</b>						
$I_{OFF}$	Sleep mode output current	EN at 0 V, single channel		0		$\mu$ A
$V_{OH}$	High-level output voltage	$I_{OH} = -4$ mA, See <a href="#">Figure 1</a>		$V_{CC} - 0.4$		V
		$I_{OH} = -20$ $\mu$ A, See <a href="#">Figure 1</a>		$V_{CC} - 0.1$		
$V_{OL}$	Low-level output voltage	$I_{OL} = 4$ mA, See <a href="#">Figure 1</a>			0.4	V
		$I_{OL} = 20$ $\mu$ A, See <a href="#">Figure 1</a>			0.1	
$V_{I(HYS)}$	Input voltage hysteresis			150		mV
$I_{IH}$	High-level input current	IN from 0 V or $V_{CC}$			10	$\mu$ A
$I_{IL}$	Low-level input current			-10		
$C_1$	Input capacitance to ground	IN at $V_{CC}$ , $V_1 = 0.4 \sin(4E6\pi t)$		2		pF
CMTI	Common-mode transient immunity	$V_1 = V_{CC}$ or 0 V, See <a href="#">Figure 4</a>	25	50		kV/ $\mu$ s

- (1) For the 5-V operation,  $V_{CC1}$  or  $V_{CC2}$  is specified from 4.5 V to 5.5 V.  
For the 3-V operation,  $V_{CC1}$  or  $V_{CC2}$  is specified from 3.15 V to 3.6 V.

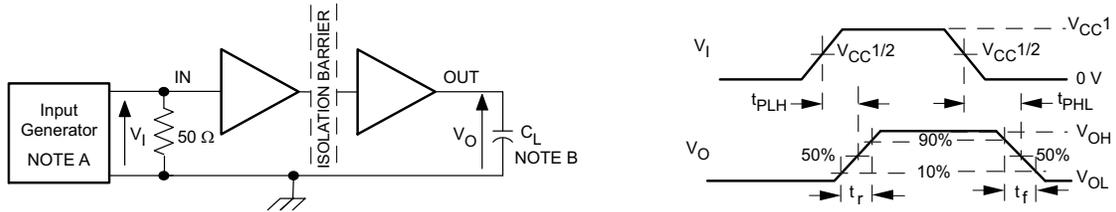
**SWITCHING CHARACTERISTICS:  $V_{CC1}$  and  $V_{CC2}$  at 3.3-V OPERATION**

over recommended operating conditions (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
$t_{PLH}$ , $t_{PHL}$	Propagation delay	See <a href="#">Figure 1</a>	45		110	ns
PWD	Pulse-width distortion $ t_{PHL} - t_{PLH} $ <sup>(1)</sup>				12	
$t_{sk(o)}$	Channel-to-channel output skew <sup>(2)</sup>				3.5	ns
$t_r$	Output signal rise time	See <a href="#">Figure 1</a>		2		
$t_f$	Output signal fall time				2	
$t_{PHZ}$	Propagation delay, high-level-to-high-impedance output	See <a href="#">Figure 2</a>		15	20	ns
$t_{PZH}$	Propagation delay, high-impedance-to-high-level output			15	20	
$t_{PLZ}$	Propagation delay, low-level-to-high-impedance output			15	20	
$t_{PZL}$	Propagation delay, high-impedance-to-low-level output			15	20	
$t_{fs}$	Failsafe output delay time from input power loss	See <a href="#">Figure 3</a>		18		$\mu$ s

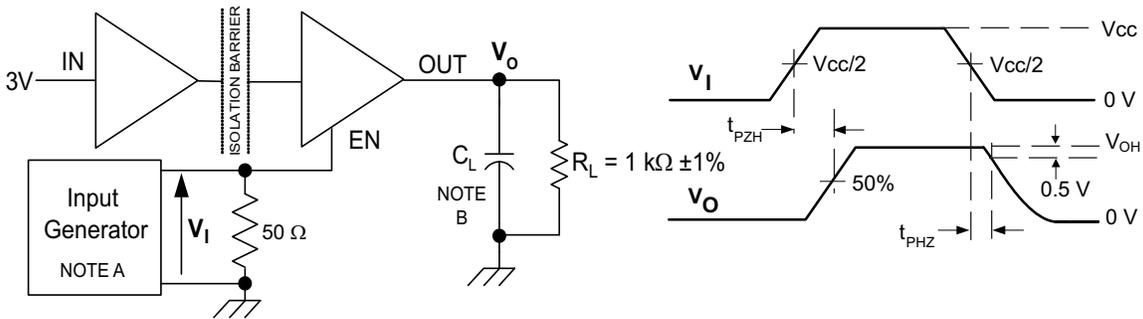
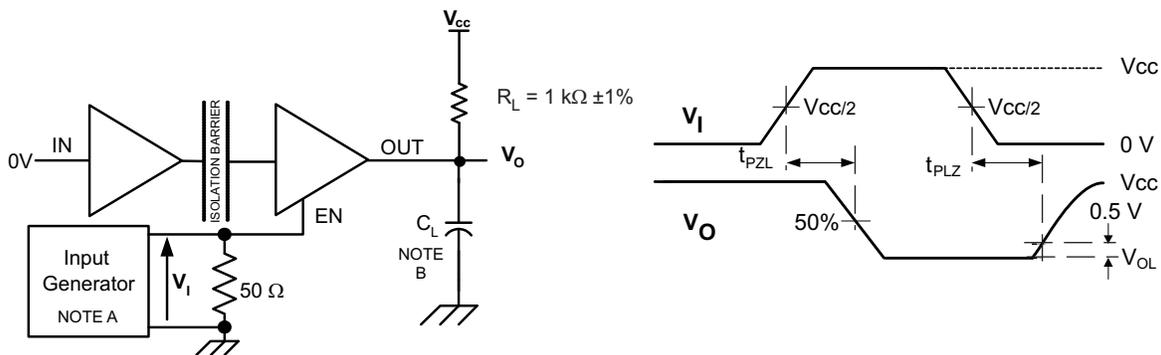
- (1) Also referred to as pulse skew.  
(2)  $t_{sk(o)}$  is the skew between specified outputs of a single device with all driving inputs connected together and the outputs switching in the same direction while driving identical specified loads.

PARAMETER MEASUREMENT INFORMATION



- A. The input pulse is supplied by a generator having the following characteristics: PRR ≤ 50 kHz, 50% duty cycle,  $t_r \leq 3$  ns,  $t_f \leq 3$  ns,  $Z_O = 50\Omega$ .
- B.  $C_L = 15$  pF and includes instrumentation and fixture capacitance within  $\pm 20\%$ .

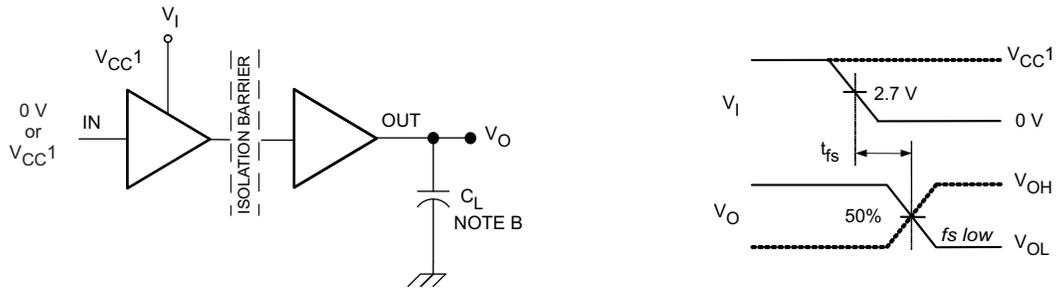
Figure 1. Switching Characteristic Test Circuit and Voltage Waveforms



- A. The input pulse is supplied by a generator having the following characteristics: PRR ≤ 50 kHz, 50% duty cycle,  $t_r \leq 3$  ns,  $t_f \leq 3$  ns,  $Z_O = 50\Omega$ .
- B.  $C_L = 15$  pF and includes instrumentation and fixture capacitance within  $\pm 20\%$ .

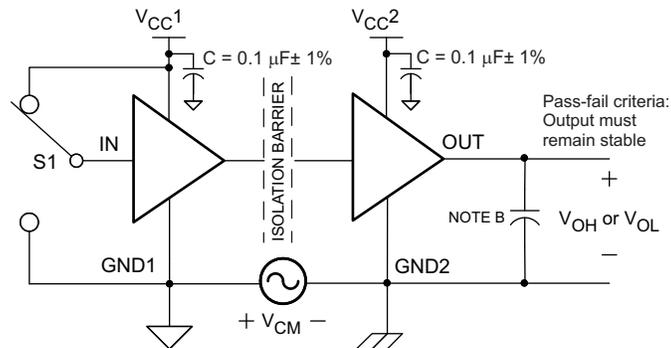
Figure 2. Enable/Disable Propagation Delay Time Test Circuit and Waveform

PARAMETER MEASUREMENT INFORMATION (continued)



- A.  $C_L = 15 \text{ pF}$  and includes instrumentation and fixture capacitance within  $\pm 20\%$ .
- B. The input pulse is supplied by a generator having the following characteristics:  $\text{PRR} \leq 50 \text{ kHz}$ , 50% duty cycle,  $t_r \leq 3 \text{ ns}$ ,  $t_f \leq 3 \text{ ns}$ ,  $Z_O = 50 \Omega$ .

Figure 3. Failsafe Delay Time Test Circuit and Voltage Waveforms



- A.  $C_L = 15 \text{ pF}$  and includes instrumentation and fixture capacitance within  $\pm 20\%$ .
- B. The input pulse is supplied by a generator having the following characteristics:  $\text{PRR} \leq 50 \text{ kHz}$ , 50% duty cycle,  $t_r \leq 3 \text{ ns}$ ,  $t_f \leq 3 \text{ ns}$ ,  $Z_O = 50 \Omega$ .

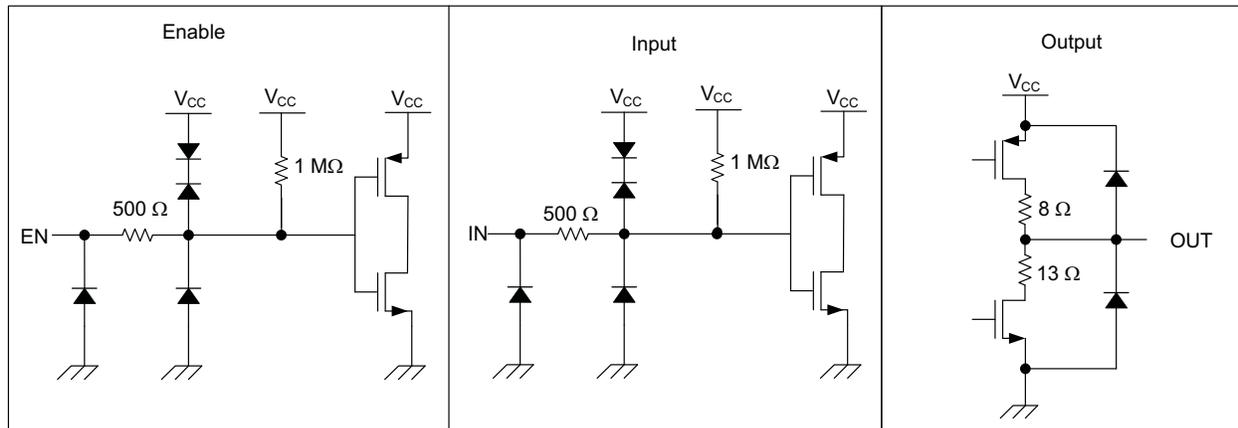
Figure 4. Common-Mode Transient Immunity Test Circuit and Voltage Waveform

**DEVICE INFORMATION**

**PACKAGE CHARACTERISTICS**

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
L(I01) Minimum air gap (Clearance)	Shortest terminal-to-terminal distance through air	8.34			mm
L(I02) Minimum external tracking (Creepage)	Shortest terminal-to-terminal distance across the package surface	8.1			mm
Minimum Internal Gap (Internal Clearance)	Distance through the insulation	0.008			mm
R <sub>IO</sub> Isolation resistance	Input to output, V <sub>IO</sub> = 500 V, all pins on each side of the barrier tied together creating a two-terminal device	>10 <sup>12</sup>			Ω
C <sub>IO</sub> Barrier capacitance Input to output	V <sub>I</sub> = 0.4 sin (4E6πt)		2		pF
C <sub>I</sub> Input capacitance to ground	V <sub>I</sub> = 0.4 sin (4E6πt)		2		pF

**DEVICE I/O SCHEMATICS**



**REGULATORY INFORMATION**

VDE	CSA	UL
Certified according to IEC 60747-5-2	Approved under CSA Component Acceptance Notice	Recognized under 1577 Component Recognition Program <sup>(1)</sup>
File Number: 40016131	File Number: 1698195	File Number: E181974

(1) Production tested ≥ 3000 Vrms for 1 second in accordance with UL 1577.

**THERMAL CHARACTERISTICS**

over recommended operating conditions (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
θ <sub>JA</sub> Junction-to-air	Low-K Thermal Resistance <sup>(1)</sup>		168		°C/W
	High-K Thermal Resistance		96.1		
θ <sub>JB</sub> Junction-to-Board Thermal Resistance			61		°C/W
θ <sub>JC</sub> Junction-to-Case Thermal Resistance			48		°C/W
P <sub>D</sub> Device Power Dissipation	V <sub>CC1</sub> = V <sub>CC2</sub> = 5.5 V, T <sub>J</sub> = 150°C, C <sub>L</sub> = 15 pF, Input a 50% duty cycle square wave			220	mW

(1) Tested in accordance with the Low-K or High-K thermal metric definitions of EIA/JESD51-3 for leaded surface mount packages.

TYPICAL CHARACTERISTIC CURVES

INPUT VOLTAGE THRESHOLD  
vs  
FREE-AIR TEMPERATURE

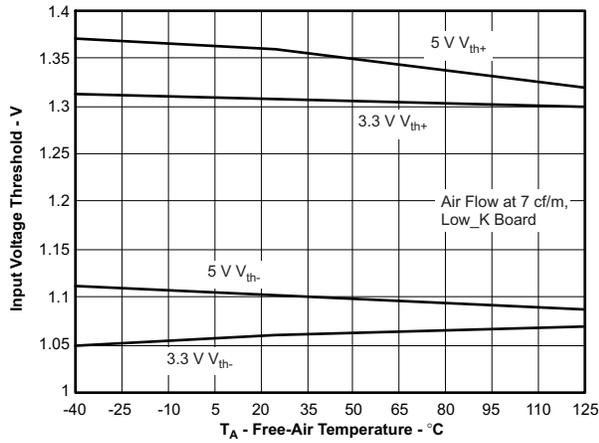


Figure 5.

V<sub>CC1</sub> FAILSAFE THRESHOLD  
vs  
FREE-AIR TEMPERATURE

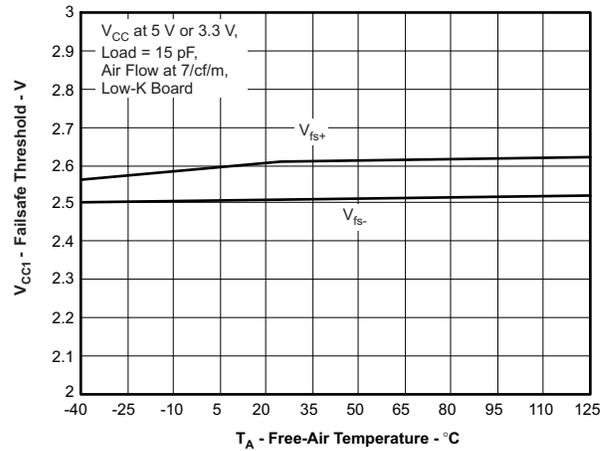


Figure 6.

HIGH-LEVEL OUTPUT CURRENT  
vs  
HIGH-LEVEL OUTPUT VOLTAGE

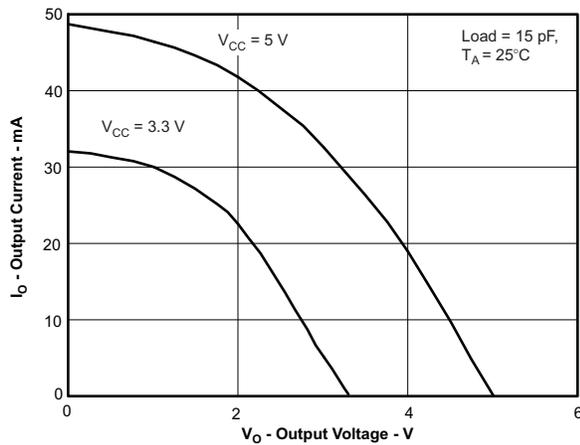


Figure 7.

LOW-LEVEL OUTPUT CURRENT  
vs  
LOW-LEVEL OUTPUT VOLTAGE

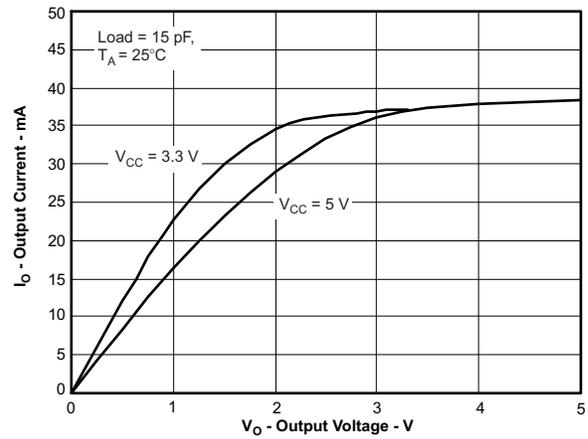


Figure 8.

APPLICATION INFORMATION

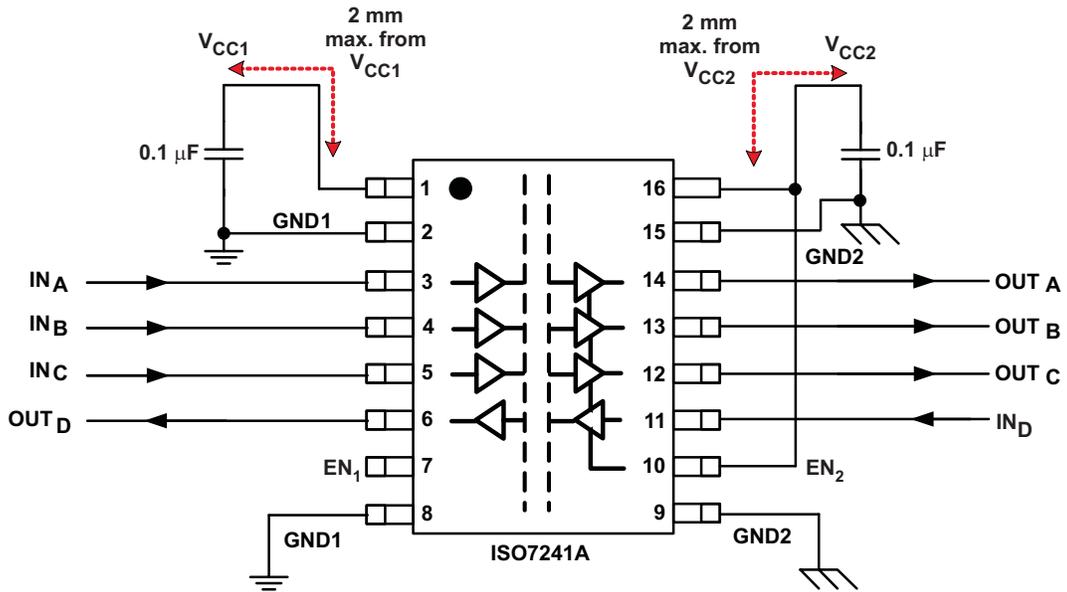


Figure 9. Typical Application Circuit

LIFE EXPECTANCY vs. WORKING VOLTAGE

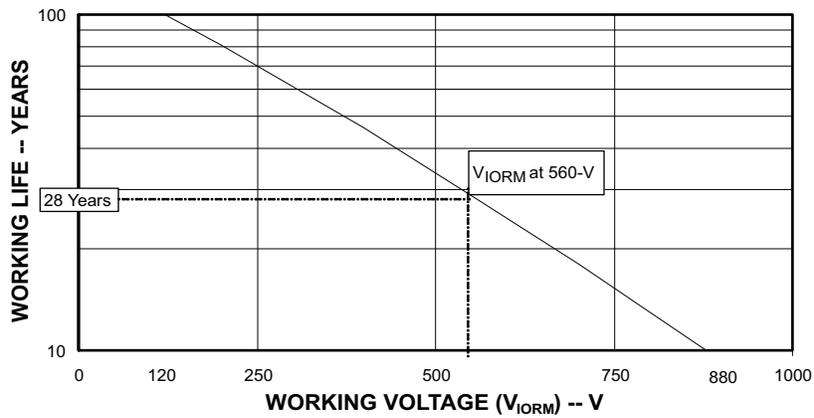


Figure 10. Time-Dependant Dielectric Breakdown Testing Results

## PRODUCT NOTIFICATION

An ISO7241A anomaly occurs when a negative-going pulse below the specified 1- $\mu$ s minimum bit width is input to the device. The output locks in a logic-low condition until the next rising edge occurs after a 1- $\mu$ s period.

Positive noise edges in pulses of less than the minimum specified 1  $\mu$ s have no effect on the device, and are properly filtered.

To prevent noise from interfering with ISO7241A performance, it is recommended that an appropriately sized capacitor be placed on each input of the device

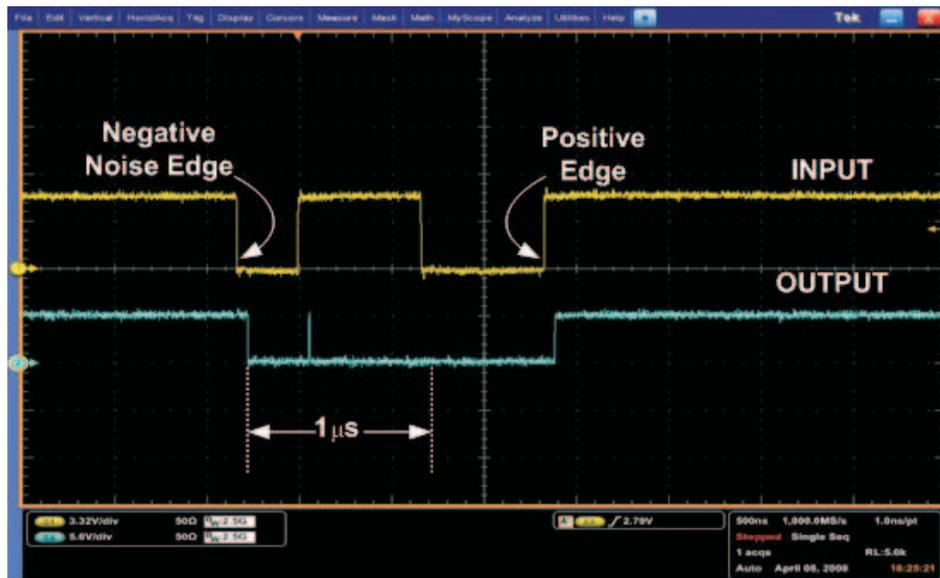


Figure 11. ISO7241A Anomaly

## PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Top-Side Markings (4)	Samples
ISO7241AMDWREP	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-55 to 125	ISO7241AM	<a href="#">Samples</a>
ISO7241AMDWREPG4	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-55 to 125	ISO7241AM	<a href="#">Samples</a>
V62/10606-01XE	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-55 to 125	ISO7241AM	<a href="#">Samples</a>

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) Only one of markings shown within the brackets will appear on the physical device.

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**OTHER QUALIFIED VERSIONS OF ISO7241A-EP :**

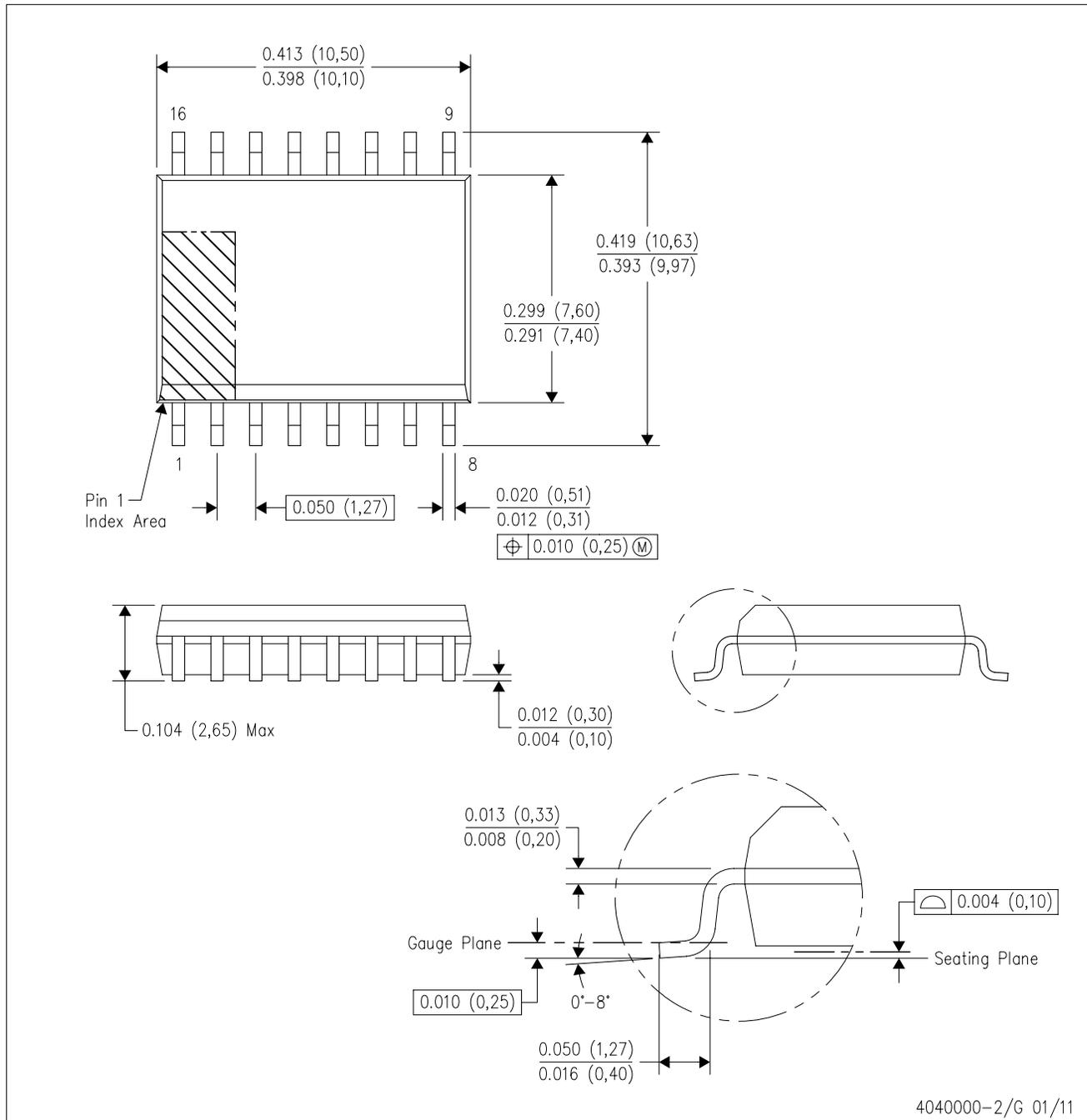
- Catalog: [ISO7241A](#)

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product

DW (R-PDSO-G16)

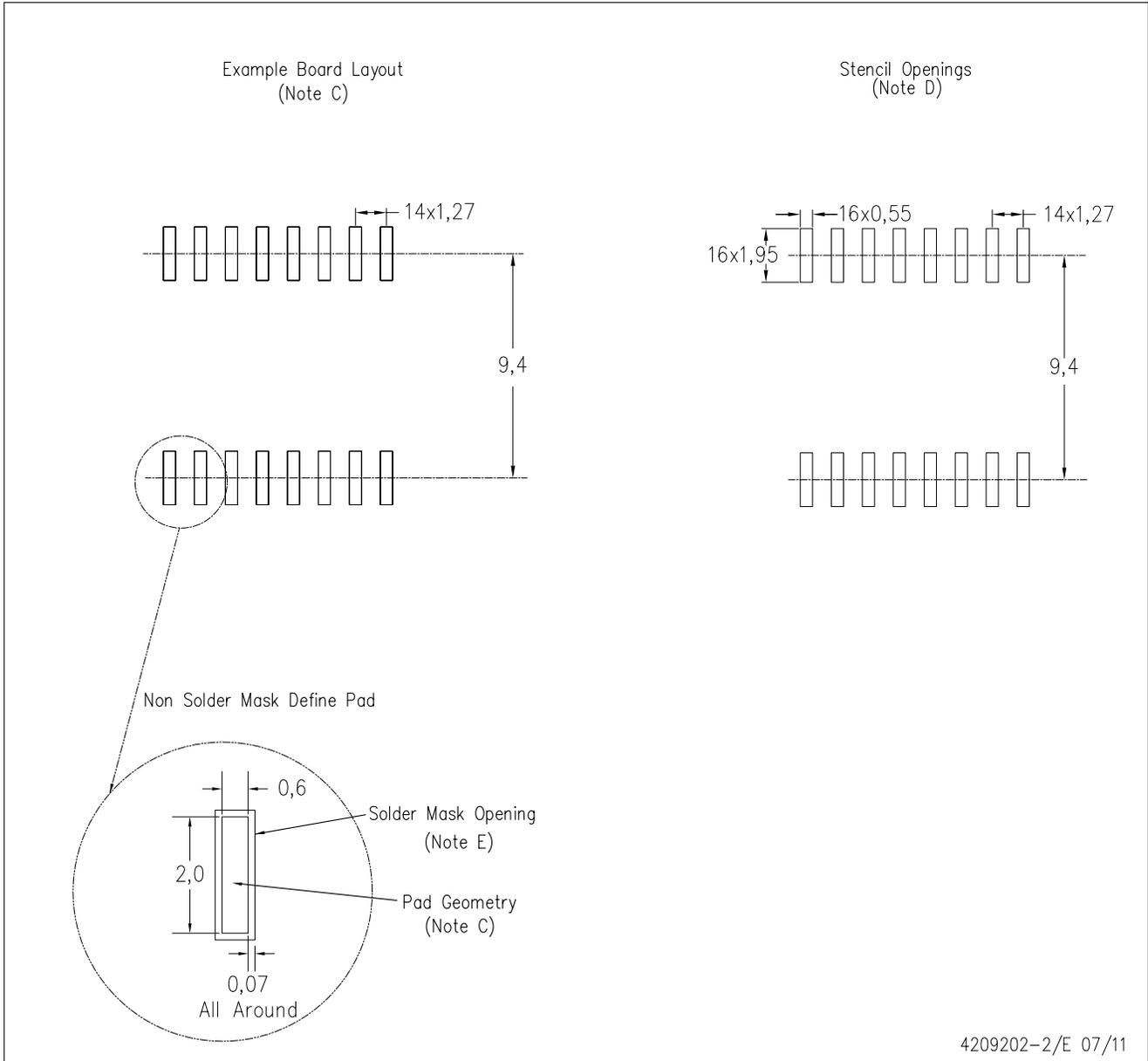
PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.
  - B. This drawing is subject to change without notice.
  - C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
  - D. Falls within JEDEC MS-013 variation AA.

DW (R-PDSO-G16)

PLASTIC SMALL OUTLINE



4209202-2/E 07/11

- NOTES:
- A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Refer to IPC7351 for alternate board design.
  - D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525
  - E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

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